Probing the Mechanism of Sodium Ion Insertion into Copper Antimony Cu2Sb Anodes

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ABSTRACT: We report experimental studies to understand the reaction mechanism of the intermetallic anode Cu2Sb with Na and demonstrate that it is capable of retaining about 250 mAh g−1 over 200 cycles when using fluoroethylene carbonate additive. X-ray diffraction data indicate during the first discharge the reaction leads to the formation of crystalline Na3Sb via an intermediate amorphous phase. Upon desodiation the Na3Sb reverts to an amorphous phase, which then recrystallizes into Cu2Sb at full charge, indicating a high degree of structural reversibility. The structure after charging to 1 V is different from that of Cu2Sb, as indicated by X-ray absorption spectroscopy and 121Sb Mössbauer spectroscopy, and is due to the formation of an amorphous Na–Cu–Sb phase. At full discharge, an isomer shift of −8.10 mm s−1 is measured, which is close to that of a Na3Sb reference powder (−7.95 mm s−1) and in agreement with the formation of Na3Sb domains. During charge, the isomer shift at 1 V (−9.29 mm s−1) is closer to that of the pristine material (−9.67 mm s−1), but the lower value is consistent with the lack of full desodiation, as expected from the potential profile and the XAS data.

1. INTRODUCTION

Recently, there has been a surge of activity to identify stable materials for sodium-ion batteries.1−4 This surge is fueled by the desire to find alternative energy storage technologies to the ubiquitous lithium-ion chemistries with an emphasis on sustainable systems using low cost and naturally abundant chemical elements. Compared to Na-ion cathodes, the investigation of Na-ion anode materials is in its infancy.1−4 Recently, there have been several significant advances in the study of sodium-ion anode materials.5−19 The discovery of new applicable chemistry in intercalation compounds, such as Na2Ti3O7,5 or hard carbons,6,7 are obvious examples. These chemistries, however, suffer from relatively low storage capacity, especially on a volumetric basis.

In order to increase the anode storage capacity and rate performance, metallic systems have been studied. The most promising elements to deliver high storage capacity are Sn,8,9 and Sb,10−13 which have large theoretical storage capacities up to 847 and 660 mAh g−1, respectively. A natural progression of this research is the investigation of intermetallic anodes which have a number of advantages over their pure counterparts such as enhanced capacity retention and faster kinetics as demonstrated for Li-ion batteries.12 This triggered the exploration of several Sb- and Sn-based intermetallic compounds, such as SnSb,13 Cu3Sn,14 Cu2Sb,15,16 AlSb,17 and Mo3Sb7−10 as well as neighboring elements like Ge19 and In.20 One potential intermetallic anode of great interest is Cu2Sb, which demonstrates high Na storage capacity (250−290 mAh g−1 or 2100−2400 mAh cm−3) and very high rate performance (10 C).15 In a previous study of the reaction end products using X-ray diffraction (XRD), we identified nanocrystalline Na3Sb (P63/mmc) as the end-member of the Na-ion electrochemical reaction,15 which was recently confirmed.16 The present contribution dwells much further into the Na-ion reaction mechanism of Cu2Sb by extending the XRD investigation using Mo Ka radiation at several electrode potentials during the first and second cycles. In addition, we report the local atomic structure of the electrode material with the aid of synchrotron-based X-ray absorption near-edge spectroscopy (XANES) and extended X-ray absorption fine structure (EXAFS) techniques at both the Cu K-edge and Sb K-edge, and the local chemical
environment of Sb using $^{125}$Sb Mössbauer spectroscopy, with the aid of Cu$_2$Sb, Sb, and Na$_3$Sb reference compounds.

2. EXPERIMENTAL SECTION

2.1. Sample Preparation. Thin films were deposited onto roughened Cu foil, or an Al foil, using dc magnetron sputtering in Ar, as reported earlier. In brief, sputter deposition conditions for Cu$_2$Sb are 30 W (power), 15 mTorr (pressure), and 5 cm target–substrate distance. With Al substrates a Cr adhesion layer was deposited at 30 W, 20 mTorr, and with a 5 cm target–substrate distance. After preparation, all the samples were stored inside an Ar-filled glovebox. For XRD and Mössbauer spectroscopy measurements, relatively thick films ($\sim$2–4 μm) were deposited onto roughened Cu foil to obtain sufficient signal. For materials used in Mössbauer spectroscopy measurements, the charge was limited to 1 V due to delamination of the comparatively thick films ($\sim$3–4 μm). For Cu K-edge XAS, the use of Al is essential to prevent absorption by the Cu collector foil. However, using Al limits the study of the charge to 1 V due to the poor adhesion of Cu$_2$Sb onto this material.

A reference powder of Na$_3$Sb was prepared inside an Ar-filled glovebox by adding stoichiometric amounts of Na (Sigma-Aldrich) and ball-milled Sb (99+%, Alfa Aesar) inside a homemade Al foil crucible placed inside a Pyrex tube. Using a Swagelok fitting connected to a vacuum valve, a primary vacuum was created inside the tube. Subsequently, the tube was placed in an oven at 175 °C. This procedure was repeated to ensure homogeneity of the compound. The recovered powder was conditioned under Ar for further XRD, XAS, and Mössbauer spectroscopy analyses.

2.2. Characterization. Electrochemical characterization was conducted at 25 °C with two-electrode 2032 coin cells prepared inside an Ar-filled glovebox using pure Na as the counter electrode and two disks of glass fiber separators impregnated with 1 M NaClO$_4$ (Sigma-Aldrich) dissolved in anhydrous fluoroethylene carbonate (PC, Sigma-Aldrich) electrolyte. When specified, 5 wt % anhydrous fluoroethylene carbonate (FEC, Sigma-Aldrich) was used as an electrolyte additive. Cycling with a constant current (CC) and with a constant current combined with a constant voltage hold (CCCV) were performed with a Maccor 4000 battery cycler. For XRD, XAS, and Mössbauer spectroscopy characterization, specimens were extracted from coin cells inside an Ar-filled glovebox, pressed onto a fiber paper to remove the excess electrolyte, sealed with Kapton tape, and packaged under Ar inside heat-sealed pouch bags. The electrodes were not washed prior to analysis since the studies focused on the bulk structures not the surface chemistries.

A Bruker D8 Advance diffractometer with Mo Kα source and Zr filter was used for XRD collection. Cycled electrodes were sealed onto a glass slide using Kapton tape. For Na$_3$Sb powder data acquisition, the ground powder was loaded inside a 0.5 mm glass capillary which was heat-sealed with a methane–oxygen torch.

Transmission electron microscopy (TEM) was performed using a Hitachi HF3300 S/TEM instrument operating at 300 kV. A 30 nm thick film deposited onto an electron transparent Si$_3$N$_4$ membrane of a TEM chip was used for characterizing the structure of the pristine material.

XAS data were recorded at the Cu K-edge (8979 eV) and Sb K-edge (30491 eV) at beamlines X19a and X18b, respectively, of the National Synchrotron Light Source, at Brookhaven National Laboratory. A Si(111) double crystal monochromator was used, and in the case of Cu K-edge measurements, the
monochromator was detuned 30% to reject higher harmonics. XAS was measured simultaneously in transmission and fluorescence. For the Cu K-edge, ion chambers for measuring $I_0$ and $I_1$ were filled with a 50:50 mixture of N$_2$:Ar. For the Sb K-edge, ion chambers for measuring $I_0$ and $I_1$ were filled with 100% Ar and a 50:50 mixture of Kr:N$_2$, respectively. Fluorescence was measured using a large area passivated implanted planar silicon (PIPS) detector perpendicular to the incident beam. All data were recorded at room temperature on samples sealed in Al pouch bags. Sb, Cu$_2$Sb, and Na$_3$Sb powders, Cu$_2$Sb pristine films, and Cu foil were measured as references. The programs ATHENA (version 0.8.061) and ARTEMIS (version 0.8.014) were used to reduce and fit the EXAFS data, respectively. Data reduction consisted of pre-edge subtraction, background determination, normalization, and spectral averaging. The $k^3$- and $k^4$-weighted EXAFS functions, $\chi(k)$, were Fourier transformed and fitted in $R$ space.

$^{121}$Sb Mössbauer spectroscopy was recorded in the constant acceleration mode using a system manufactured by SEE Co., Edina, MN. The source was 100 $\mu$Ci of $^{121m}$Sn in BaSnO$_3$ at room temperature, and a Xe−CH$_4$ proportional counter was used to detect the sum of the 37.2 keV $\gamma$-rays and 8 keV escape peak. Several thick electrodes, providing around 20 mg of starting Cu$_2$Sb material, were measured simultaneously to provide enough absorption. The samples were cooled to 6−7 K under vacuum in a closed-cycle cryogen-free refrigerator (Janis, Wilmington, MA, and SEE Co.), partly to increase the Mössbauer fraction and partly to suppress the materials oxidation. The velocity scale was calibrated with an $^{57}$Fe absorber and a Rh$^{57}$Co source and is quoted relative to the BaSnO$_3$ source. The spectra were fitted with a custom Mössbauer program using a Lorentzian line profile. Powders of Sb, Cu$_2$Sb, and Na$_3$Sb were used as references.

3. RESULTS AND DISCUSSION
3.1. Electrochemical Properties of Cu$_2$Sb Anode versus Na. The structure of Cu$_2$Sb (P4/nmm) is a tetragonal unit cell (Figure S1), of which a subcell comprising a single Cu$_2$Sb formula unit is depicted in Figure 1a. The tetragonal structure can also be described as a distorted face-centered cubic (fcc) Sb structure with dimensions of $\sim$5.6 $\times$ 5.6 $\times$ 6.1 Å (Figure 1a). Within this pseudo-fcc structure, half of the Cu atoms (Cu1, green atoms) occupy half of the tetrahedral sites whereas the other half (Cu2, blue atoms) are located in the distorted octahedra. The structure of the starting films has been characterized by TEM. The material deposited onto a SiN$_x$ window is composed of small grains with diameters from 5 to 20 nm. The presence of a crystalline material is clearly evidenced by the presence of lattice fringes and variations in contrast due to differences in crystal orientation (Figure 1b).

The electrochemical properties of Cu$_2$Sb as an anode material for Na-ion batteries are presented in Figure 2. The cycling performance of the films cycled in NaClO$_4$ dissolved in PC was formerly found to be satisfactory for tens of cycles only (blue curve, Figure 2a). The use of appropriate electrolyte additives, such as FEC, promotes the cycle life of metallic anodes significantly thanks to the formation of a more stable inorganic solid electrolyte interphase (SEI) layer. Two electrodes cycled with FEC additive show significantly improved capacity retention (Figure 2a, green and red curves). For these thicker electrodes, the slow increase of capacity during the first few cycles is related to the use of FEC, which induces the presence of larger overpotentials (0.15−0.2 V) during discharge that eventually decrease upon further cycling (Figure 2b). The presence of larger overpotentials was previously observed in the case of Ge and was measured systemically for Mo$_2$Sb$_3$, AlSb, and SnSb thin film electrodes of similar thicknesses (not presented). The stable capacities around 250 mAh g$^{-1}$, measured for these thicker films (600−850 nm), are somewhat lower compared to the thin electrode (290 mAh g$^{-1}$). This difference is due to the better diffusion kinetics of thinner films, which allows access to almost all the electrode material volume under the present experimental conditions (80 $\mu$A cm$^{-2}$). Nonetheless, it is clear that the application of 5 wt % FEC to the electrolyte greatly improves the capacity retention of thicker electrodes over hundreds of cycles with a stable capacity of about 250 mAh g$^{-1}$ (Figure 2a). This important improvement is likely related to the formation of a more stable inorganic SEI layer rich in NaF, as we discussed earlier, and demonstrates the potential of Cu$_2$Sb anode materials for Na-ion batteries. When a thicker film is used (850 nm), the capacity declines faster than for a thinner film (600 nm) due to the larger volume changes of the thicker layer.

The electrochemical reaction of Cu$_2$Sb electrodes during the first two cycles is now discussed. During the initial sodiation, the potential profile is dominated by a pronounced plateau centered around 0.35 V. The associated capacity is significantly lower than the peak capacity at 0.1 V that is typical for Cu$_2$Sb electrodes in NaClO$_4$ dissolved in PC. This significant decrease in capacity compared to that in PC/FEC is due to an overpotential related to the formation of an SEI layer rich in NaF.
larger than during the following discharges, which also show a slope around 0.5 V. The longer discharge plateau is mostly related to Coulombic losses due to electrolyte decomposition since the reaction during the initial discharge consists not only of the electrode bulk reaction but also shows the passivation of the electrode, current collector, and coin cell hardware surfaces in contact with the electrolyte. The discharge (sodiation) capacity amounts to about 400 mAh g$^{-1}$ or 3.7 Na/Sb, which corresponds to the bulk reaction (Na-ion insertion into Cu$_2$Sb as much as 3 Na/Sb expected) and the surface reactions discussed above. The charge voltage profiles are virtually identical with a large plateau around 0.75 V and a small slope near 0.9 V. The charge (desodiation) capacity measured on a thick electrode (3 μm) is equal to about 250 mAh g$^{-1}$ or 2.3 Na/Sb. This indicates that either full sodiation did not occur during discharge or that some Na is trapped inside in the material. Since the structural characterization data (XRD, XAS, Mössbauer spectroscopy, see next) support the occurrence of full sodiation, we suppose that the lower reversible storage capacity results from the absence of full desodiation due to diffusion limitations, in particular for thicker films. XPS data collected on Cu$_2$Sb$^{15}$ samples show lower than expected binding energies of the Sb core levels upon desodiation consistent with the hypothesis of trapped Na.

### 3.2. Characterization of the Electrode Material Structure by XRD

The mechanism during the reaction with Li is first discussed to serve as a reference for the reaction with Na. During the reaction with Li, all Cu2 atoms from the distorted octahedral sites are substituted by Li atoms, which leads to a slight displacement of the Sb atoms to form an ideal fcc cell in the form of Li$_2$Cu$_{11}$Sb ($0 < x < 1$). Further insertion of Li ions takes place in the tetrahedral sites with cooperative displacement of the Cu1 atoms to the neighboring tetrahedral site. Overall, these two steps lead to the extrusion of one Cu atom and the insertion of two Li atoms per formula unit of Cu$_2$Sb. The reaction thereby results in the formation of cubic Li$_2$Cu$_{13}$Sb ($I4_3$m) with significantly elongated Sb–Sb bonds and a lattice parameter of 6.27 Å. Li$_2$Cu$_{13}$Sb structure is an Sb fcc array with one Li and all Cu alternately occupying the eight tetrahedral sites and the second Li occupying the four octahedral sites. Further reaction takes place by substituting the Cu atoms remaining in the tetrahedral sites to form cubic Li$_2$Sb ($Fm\overline{3}m$) with a lattice parameter of 6.56 Å. This structure is normally only obtained at high pressures but known to form electrochemically at room temperature and adopts an Sb fcc array with full occupation of the tetrahedral and octahedral sites by Li.$^{22–24}$

The investigation of the electrode structure at various degrees of sodiation during the first and second cycles, as marked by the red closed circles labeled A to L in Figure 2b, has been studied by XRD using Mo Kα radiation. The corresponding XRD patterns are presented in Figure 3, which also includes the pattern for a pristine film. For the cycled electrodes, the broad hump at low angle originates from the Kapton material. The pristine film material is composed of nanocrystallites with broad peaks centered on the positions expected for P4/mmm Cu$_2$Sb (blue bars). The results show some preferred crystallite orientation within the thin film, as evidenced by (111) and (112) peaks at 15.9° and 19.7° that are stronger than for the reference pattern (blue bars). This analysis does not take into account that the film was measured with a fixed divergence slit, which for thin films does not respect the constant volume approximation. In fact, the amount of material present in the beam at low diffraction angles can be significantly larger than at larger angles, thereby minimizing the intensity of the (111) and (121) compared to the lower angle peaks.

During discharge (Na-ion insertion), the reaction starts by the conversion of Cu$_2$Sb into a material with no characteristic diffraction lines (position A), such as possibly an amorphous phase (Figure 3). The reaction further progresses by the formation of nanocrystalline Na$_2$Sb (see lines at 8.5–10°, 15–16°, and 17.5°, positions B–D; see Figure S3 for clarity) and the absence of diffraction lines from other phases except Cu$_2$Sb. It is clear that the diffraction peaks of Cu$_2$Sb, especially those from 12° to 16°, the strong (112) peak at 19.7°, and the (020) peak at 20.4° all decrease in intensity. At point D, the diffraction lines from Cu$_2$Sb have almost vanished. These results suggest that Cu$_2$Sb has converted completely into an amorphous phase and Na$_2$Sb around position D. Moreover, the gradual consumption of Cu$_2$Sb and the concomitant formation of Na$_2$Sb suggest a reaction front from the surface to the bulk of the film. By comparison with the electrochemical reaction of pure Sb with Na, the formation of crystalline Na$_2$Sb intermediate is not expected, and instead an amorphous phase formed after as also measured here. Further sodiation from E to F leads to the growth of the peaks associated with Na$_2$Sb, whereas the peaks related to Cu$_2$Sb are not present anymore (Figure S2). The growth of the peaks related to Na$_2$Sb can therefore be attributed to the sodiation of the amorphous phase.

During charge (Na-ion removal, positions G to J′), XRD data indicate the Na$_2$Sb converts into an amorphous phase as no lines due to crystalline phases are observed until point J′. At position J′ (CCCV to 1.5 V with cutoff of C/30) the presence of broad humps related to Cu$_2$Sb are observed from 13° to 16° and around 20.5°. At position J′, which is an electrode prepared with a more thorough desodiation by employing a current cutoff of C/30, diffraction lines of nanocrystalline Cu$_2$Sb are now clearly visible. The presence of these lines demonstrates that the reaction can proceed reversibly if a deep
extraction of Na is conducted at 1.5 V and strengthens the view that full structural reversibility requires higher electrode potentials and/or longer hold times. During the second discharge, the addition of Na on the new slope centered around 0.5 V (positions K and L) results in the presence of an amorphous phase. Since the second charge is very similar to the first charge (Figure 2b), we suspect that further addition of Na from point L to 0 V results in the formation of crystalline Na3Sb.

During the reaction of Cu2Sb with Na, the formation of a solid solution or of a new intermediate crystalline phase is not evidenced. This is suggested by the reaction of Sb, which proceeds by the formation of an amorphous phase until hexagonal P63/mmc Na3Sb crystallizes. Although the formation of the high-pressure cubic Fm3m Na3Sb phase has been evidenced to a very small extent during the electrochemical reaction, it was found that the small amount of this phase transforms into the room temperature hexagonal Pb3/mmc polymorph at full discharge. This reaction is very different from that of Sb with Li during which hexagonal Li3Sb forms, followed by the formation of the high-pressure cubic Fm3m Li3Sb phase. The analysis of these differences in reaction scheme suggests that the reaction of Cu2Sb with Na is not likely to proceed using the same pathway as with Li. The reaction of Cu2Sb with Li discussed earlier is essentially governed by the transformations of a compactfcc Sb array, which may explain why the reaction with Na proceeds by the formation of an amorphous phase. In summary, our results support that the reaction can be written as Cu2Sb + 3Na ↔ Na3Sb + 3Cu via the formation of an intermediate amorphous Na−Cu−Sb phase of varying Na content possibly coexisting with extruded Cu. The local atomic structure of the electrode material is discussed next.

### 3.3. Local Atomic Environment of the (Dis)charged Electrode Materials

The discussion of the local environment of Sb atoms in Cu2Sb, Sb, and Na3Sb phases is important, as it will serve as a basis for the forthcoming discussion of the local atomic structure of the electrodes measured by XAS and Mössbauer spectroscopy. Figure 4 presents the first and second neighbors of Sb atoms for (a) Sb (R3m), (b) Cu2Sb (P4/nmm), and (c) Na3Sb (P63/mmc) with additional projections given in Figure S4. The corresponding interatomic distances are listed in Table S1. The first coordination shell in pure Sb is composed of a distorted octahedron with 3 Sb atoms ~2.90 Å and 3 Sb atoms ~3.36 Å. The second coordination shell is composed of 12 Sb atoms with 6 atoms ~3.41 Å and the other 6 atoms ~4.51 Å. In the case of Cu2Sb, the Sb atoms are 9-fold coordinated by Cu atoms positioned from 2.63 to 2.84 Å. The second coordination shell is composed of 1 Cu atom ~3.48 Å, 4 Sb atoms ~3.74 Å, and 4 Sb atoms ~4.00 Å. Hence, the Sb atoms are fairly isolated from each other in the structure, as also evident from the distorted fcc representation discussed earlier (Figure 1a). In Na3Sb, Sb is 11-fold coordinated by Na atoms located from 3.10 to 3.48 Å with 5 atoms from 3.10 to 3.17 Å and the other 6 atoms at 3.48 Å. The second coordination shell is relatively further away with 6 Sb atoms ~5.37 Å and 6 Na and 6 Sb atoms at ~5.68 Å. In Na3Sb, Sb atoms are significantly isolated.

The atomic environment of Cu was probed using XAS at the Cu K-edge and Sb K-edge. XANES at the Cu K-edge of Cu2Sb thin film electrodes (Figure 5a), along with the Cu2Sb powder and Cu foil standards, are discussed next. The inset shows a magnified region around the step edge. Qualitatively, it appears that the spectra of the pristine film and electrode charged at 1 V are nearly identical to the Cu2Sb powder. Comparing the spectra in greater detail over the entire range indicates that the pristine film is essentially identical to the powder while the film charged at 1 V shows quantitative deviations at 8990, 9000, and 9022 eV as well as a small shift in the edge position toward lower photon energy. The changes above the edge are likely changes in the EXAFS oscillations resulting from small structural changes. The shift of the edge toward lower photon energy indicates a small reduction in oxidation state of the Cu compared to pure Cu2Sb. For the electrode discharged at 0 V, a feature at low photon energy similar to the Cu foil is measured. At higher energies, the spectrum lies in between that of Cu2Sb and Cu, suggesting that the electrode material might contain regions of Na1−Cu3−ySb and metallic Cu.

The Fourier transform of the k3-weighted EXAFS at the Cu K-edge for the same samples is shown in Figure 5b. As in XANES, EXAFS of the pristine film is virtually identical to the Cu2Sb powder. The results of the fit confirm that the pristine film has essentially the same structural parameters as the Cu2Sb powder over the first three nearest neighbors (Table S2). The electrode discharged at 0 V closely resembles the Cu foil although the number of Cu nearest neighbors is significantly smaller in this film (6.7 ± 0.5) compared to bulk Cu (12). The smaller coordination number indicates that the average Cu particle/domain size is very small (few nanometers), which could be expected from a displacement/extrusion reaction of...
Cu by Na at the atomic level. Inclusion of scattering paths contained in Cu$_2$Sb did not improve the fit and/or were physically unrealistic (e.g., negative amplitudes or unrealistic nearest-neighbor distances). The EXAFS data collected for the electrode charged at 1 V look significantly different from either Cu$_2$Sb or metallic Cu. The Fourier transform of the EXAFS data is skewed toward low $R$ compared to larger $R$ in the Cu$_2$Sb powder. The results of the fit indicate generally smaller coordination numbers, but the ratio is essentially the same as in the Cu$_2$Sb powder. Note that the $R$-factor is significantly worse than in any of the other samples analyzed, which suggests that the structure might not be adequately captured by modeling using environments of either Cu$_2$Sb or metallic Cu and highlight the role of the remaining Na at 1 V creating a disordered structure.

The Sb K-edge for the Cu$_2$Sb thin film electrodes along with the Cu$_2$Sb, Sb, and Na$_3$Sb powder standards are discussed next (Figure 6 and Figure S5). The XANES (Figure S5) provides little information as the changes in valence electronic density on the K-shell electron density can be expected to be very small. For this reason, the Sb environment was also studied with $^{121}$Sb Mössbauer spectroscopy (Figure 7), which is sensitive to electron density variation in the tens of neV. The FT of the EXAFS data for the pristine Cu$_2$Sb film and powder are fairly close to that measured for the electrode discharged at 2 V (Figure 6). At 0 V there is an important change, compared to the other materials, where the structure has little backscattering at small interatomic distances. The weak backscattering is likely due to the absence of Sb backscatterers at distances below 5 Å (Table S3), as also found for the Na$_3$Sb reference powder. The low atomic number of Na compared to the energy of more than 30 keV may explain why it does not significantly contribute to the signal at low interatomic distances. The Cu K-edge XAS results support the formation of pure Cu, and overall the XAS results at both K edges converge to explain the formation of Na$_3$Sb domains.
The local atomic ordering for the electrode at 1 V is significantly different than that at 2 V, as also found with Cu K-edge data. This is evident from the significantly larger R and Debye–Waller factors and interatomic distances compared to the pristine or charged electrode (Table S3). These results further highlight that the presence of remaining Na in the structure has a profound impact on the local ordering, which leads to the presence of a disordered structure measured as an amorphous phase by XRD (Figure 3b).

The chemical environment of Sb atoms has been further investigated using $^{121}$Sb Mössbauer spectroscopy, which is the recoil-free resonant absorption of $\gamma$-rays. This technique measures the relative changes in electronic density at the nucleus as a result of variations in valence electron densities and thereby allows the identification of the chemical environment of the probed atom.\(^{25}\) This technique has proved to be very powerful at elucidating the reaction mechanism of various Sb-based anodes for Li-ion batteries.\(^{26}\) The spectra for the cycled electrodes as well as for a variety of reference materials including phase pure Na$_3$Sb (Figure S6) are presented in Figure 7 with corresponding isomer shift values provided in Table 1.

![Figure 6. Sb K-edge EXAFS data for the pristine Cu$_2$Sb thin film and powder, electrode thin films discharged at 0 V and charged at 2 V, and for Sb and Na$_3$Sb powders. The radial distance is not corrected for the phase shift.](Image 60x263 to 300x749)

![Figure 7. $^{121}$Sb Mössbauer spectroscopy data for Sb powder, Cu$_2$Sb powder, Cu$_2$Sb thin film, electrode thin film charged at 1 V and discharged at 0 V, and Na$_3$Sb reference powder.](Image 75x289 to 286x497)

The isomer shift of the starting Cu$_2$Sb powder (−9.67 mm s$^{-1}$) is in fairly good agreement with the value of −9.2 mm s$^{-1}$ predicted by Sharma et al. using density functional theory calculations.\(^{27}\) They also reported a predicted value of −8.2 mm s$^{-1}$ for InSb, which is rather close to the experimental value of −8.6 mm s$^{-1}$,\(^{28}\) and in both cases the predictions slightly overestimate the experimental isomer shift values by about 0.4 mm s$^{-1}$. The isomer shift of Cu$_2$Sb is much more positive than that of our Sb powder (−11.85 mm s$^{-1}$) or of SnSb (−10.5 mm s$^{-1}$)\(^{28}\) but is more negative than the values reported for other Sb intermetallics such as AlSb, GaSb, InSb, and CdSb characterized by isomer shifts from −7.8 to −8.6 mm s$^{-1}$.\(^{28}\) For $^{121}$Sb Mössbauer spectroscopy, the increasing (decreasing) isomer shift reflects a decrease (increase) in the Sb electron density at the nucleus. The electron density is dependent on the number of 5s and 5p electrons and generally increases with the increase of 5s electrons and with the decrease of 5p electrons.\(^{28}\) For Cu$_2$Sb, it is clear that the isomer shift is less positive than those for the M–Sb intermetallics of In, Cd, Ga, and Al, especially Al, which can be related to the larger electronegativity of Cu (1.90), using Pauling’s scale for example, compared to In (1.78), Ga (1.81), Cd (1.69), and Al (1.61). Conversely, the more positive isomer shift of Cu$_2$Sb compared to SnSb or Sb can be associated with the larger electronegativity of Sn (1.96) and Sb (2.05) compared to Cu. As Sb is the most electronegative element in this series, alloying with an atom of lower electronegativity will result in a higher number of effective valence electrons overall. As such, the electronic configuration of Sb (5s = 1.91/5p = 3.09, formally 5s = 2/5p = 3), effectively changes with an increase of the 5p electrons but a decrease of the 5s electrons\(^{28}\) and leads to the variety of isomer shifts discussed above.

The thin film material created by sputtering the powder target is characterized by a spectrum with an isomer shift (−9.65 mm s$^{-1}$) quasi-identical to that of the powder, which confirms that the local atomic ordering of the film is similar to that of the powder. This result further supports the findings from the other characterizations. After a discharge to 0 V and a charge at 1 V, a spectrum characterized by an isomer shift of −9.29 mm s$^{-1}$ is measured, which is fairly close to that of the pristine material (−9.65 mm s$^{-1}$). The difference of about 0.35 mm s$^{-1}$ can be related to the absence of full desodiation due to the use of the charge cutoff of 1 V. This result is in good agreement with the XAS and XRD results that indicated a significant structural disordering of the electrode material at 1 V concomitant with the presence of an amorphous phase. At full sodiation (0 V), the spectrum is composed of a singlet with an isomer shift of −8.10 mm s$^{-1}$, which is very close to what is measured for the Na$_3$Sb reference powder (−7.95 mm s$^{-1}$).

### Table 1. $^{121}$Sb Mössbauer Isomer Shift ($\delta$) Measured for the Various Cu$_2$Sb Electrodes and Reference Materials

<table>
<thead>
<tr>
<th>Sample</th>
<th>$\delta$ (mm s$^{-1}$)</th>
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<tbody>
<tr>
<td>Na$_3$Sb powder</td>
<td>−9.29 ± 0.04</td>
</tr>
<tr>
<td>Cu$_2$Sb powder</td>
<td>−9.67 ± 0.04</td>
</tr>
<tr>
<td>Cu$_2$Sb film</td>
<td>−9.65 ± 0.05</td>
</tr>
<tr>
<td>Sb powder</td>
<td>−11.85 ± 0.06</td>
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The isomer shift value obtained for the Na$_3$Sb powder is in good agreement with the reported value of $-0.67$ mm s$^{-1}$ with respect to the isomer shift of InSb, which is equal to $-7.93$ mm s$^{-1}$ assuming $-8.6$ mm s$^{-1}$ for the isomer shift of InSb with respect to a BaSnO$_4$ source. The slightly more negative isomer shift measured for the discharged electrodes (c. $-8.10$ mm s$^{-1}$) compared to Na$_3$Sb (c. $-7.95$ mm s$^{-1}$) can be related to the absence of full sodiation of the very thick films employed for the Mössbauer measurements; nonetheless, the result suggests that the final discharge product is Na$_3$Sb, as evidenced by XRD and XAS results.

4. CONCLUSIONS

The electrochemical performance of Cu$_2$Sb thin film electrodes during the reaction with Na has been revisited using FEC as an electrolyte additive. The addition of FEC is found to drastically improve the electrode capacity retention with about 250 mAh g$^{-1}$ retained for 200 cycles. On the other hand, the use of FEC increases the overpotentials during the first discharges, as systematically found on several other (inter)metallic anode systems. The reaction mechanism of Cu$_2$Sb anode has been unraveled using XRD and Cu K-edge and Sb K-edge XAS. In addition, the present paper discloses for the first time the Mössbauer isomer shift of Cu$_2$Sb ($-9.67$ mm s$^{-1}$ vs BaSnO$_4$) as well as the changes in hyperfine parameters for the (dis)-charged electrodes. The XRD results indicate that Cu$_2$Sb can undergo a fully reversible transformation into Na$_3$Sb via an amorphous phase. The formation of Na$_3$Sb domains at full discharge (0 V) is further confirmed by XAS and Mössbauer spectroscopy results with the aid of a Na$_3$Sb reference compound. The formation of Cu$_2$Sb, indicating full structural reversibility, is evidenced by XRD and XAS results when the charge is conducted up to 1.5 or 2 V with lower cutoff currents. Finally, the results demonstrate that restricting the charge voltage to 1 V results in the formation of a disordered structure (amorphous phase).

ASSOCIATED CONTENT

1. Supporting Information
Crystal structure representations, XRD, XAS, and tables with fits to the data. This material is available free of charge via the Internet at http://pubs.acs.org.

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Notes
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